

# RF Power Field Effect Transistors

## N-Channel Enhancement-Mode Lateral MOSFETs

Designed for CDMA base station applications with frequencies from 1800 to 2200 MHz. Can be used in Class AB and Class C for all typical cellular base station modulation formats.

- Typical Doherty Single-Carrier W-CDMA Performance:  $V_{DD} = 32$  Volts,  $I_{DQA} = 150$  mA,  $V_{GSB} = 1.5$  Vdc,  $P_{out} = 10$  Watts Avg., IQ Magnitude Clipping, Channel Bandwidth = 3.84 MHz, Input Signal PAR = 9.9 dB @ 0.01% Probability on CCDF.

| Frequency | $G_{ps}$<br>(dB) | $\eta_D$<br>(%) | Output PAR<br>(dB) | ACPR<br>(dBc) |
|-----------|------------------|-----------------|--------------------|---------------|
| 2025 MHz  | 18.2             | 42.6            | 7.3                | -34.8         |

- Capable of Handling 5:1 VSWR, @ 32 Vdc, 2017.5 MHz, 50 Watts CW <sup>(1)</sup> Output Power (3 dB Input Overdrive from Rated  $P_{out}$ )
- Typical  $P_{out}$  @ 3 dB Compression Point  $\approx$  50 Watts CW <sup>(1)</sup>

### Features

- Production Tested in a Symmetrical Doherty Configuration
- 100% PAR Tested for Guaranteed Output Power Capability
- Characterized with Series Equivalent Large-Signal Impedance Parameters and Common Source S-Parameters
- Internally Matched for Ease of Use
- Integrated ESD Protection
- Greater Negative Gate-Source Voltage Range for Improved Class C Operation
- Designed for Digital Predistortion Error Correction Systems
- RoHS Compliant
- In Tape and Reel. R3 Suffix = 250 Units, 56 mm Tape Width, 13 inch Reel. For R5 Tape and Reel option, see p. 15.

**Table 1. Maximum Ratings**

| Rating                                                       | Symbol    | Value        | Unit      |
|--------------------------------------------------------------|-----------|--------------|-----------|
| Drain-Source Voltage                                         | $V_{DSS}$ | -0.5, +65    | Vdc       |
| Gate-Source Voltage                                          | $V_{GS}$  | -6.0, +10    | Vdc       |
| Operating Voltage                                            | $V_{DD}$  | 32, +0       | Vdc       |
| Storage Temperature Range                                    | $T_{stg}$ | - 65 to +150 | °C        |
| Case Operating Temperature                                   | $T_C$     | 150          | °C        |
| Operating Junction Temperature <sup>(2,3)</sup>              | $T_J$     | 225          | °C        |
| CW Operation @ $T_C = 25^\circ\text{C}$<br>Derate above 25°C | CW        | 42.4<br>0.17 | W<br>W/°C |

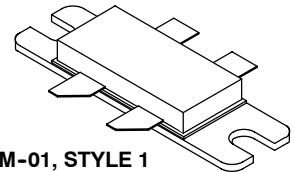
**Table 2. Thermal Characteristics**

| Characteristic                                                                                                                                                                                                                                     | Symbol          | Value <sup>(3,4)</sup> | Unit |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------|------------------------|------|
| Thermal Resistance, Junction to Case<br>Case Temperature 78°C, 10 W CW, 32 Vdc, $I_{DQA} = 150$ mA, $V_{GSB} = 1.5$ Vdc, 2017.5 MHz<br>Case Temperature 82°C, 40 W CW <sup>(1)</sup> , 32 Vdc, $I_{DQA} = 150$ mA, $V_{GSB} = 1.5$ Vdc, 2017.5 MHz | $R_{\theta JC}$ | 2.11<br>1.50           | °C/W |

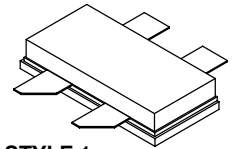
- Exceeds recommended operating conditions. See CW operation data in Maximum Ratings table.
- Continuous use at maximum temperature will affect MTTF.
- MTTF calculator available at <http://www.freescale.com/rf>. Select Software & Tools/Development Tools/Calculators to access MTTF calculators by product.
- Refer to AN1955, *Thermal Measurement Methodology of RF Power Amplifiers*. Go to <http://www.freescale.com/rf>. Select Documentation/- Application Notes - AN1955.

**MRF7P20040HR3**  
**MRF7P20040HSR3**

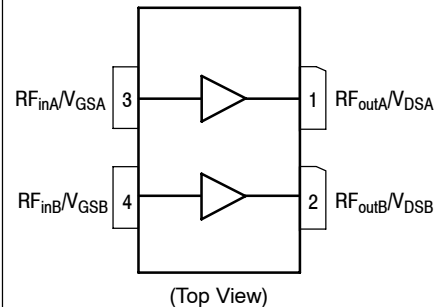
**2010-2025 MHz, 10 W AVG., 32 V**  
**SINGLE W-CDMA**  
**LATERAL N-CHANNEL**  
**RF POWER MOSFETs**



**CASE 465M-01, STYLE 1**  
**NI-780-4**  
**MRF7P20040HR3**



**CASE 465H-02, STYLE 1**  
**NI-780S-4**  
**MRF7P20040HSR3**



**Figure 1. Pin Connections**

**Table 3. ESD Protection Characteristics**

| Test Methodology                      | Class        |
|---------------------------------------|--------------|
| Human Body Model (per JESD22-A114)    | 1A (Minimum) |
| Machine Model (per EIA/JESD22-A115)   | B (Minimum)  |
| Charge Device Model (per JESD22-C101) | IV (Minimum) |

**Table 4. Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

**Off Characteristics** <sup>(1)</sup>

|                                                                                                   |           |   |   |    |                 |
|---------------------------------------------------------------------------------------------------|-----------|---|---|----|-----------------|
| Zero Gate Voltage Drain Leakage Current<br>( $V_{DS} = 65\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ ) | $I_{DSS}$ | — | — | 10 | $\mu\text{Adc}$ |
| Zero Gate Voltage Drain Leakage Current<br>( $V_{DS} = 32\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ ) | $I_{DSS}$ | — | — | 1  | $\mu\text{Adc}$ |
| Gate-Source Leakage Current<br>( $V_{GS} = 5\text{ Vdc}$ , $V_{DS} = 0\text{ Vdc}$ )              | $I_{GSS}$ | — | — | 1  | $\mu\text{Adc}$ |

**On Characteristics** <sup>(1)</sup>

|                                                                                                                  |              |     |      |     |     |
|------------------------------------------------------------------------------------------------------------------|--------------|-----|------|-----|-----|
| Gate Threshold Voltage<br>( $V_{DS} = 10\text{ Vdc}$ , $I_D = 33.5\text{ }\mu\text{Adc}$ )                       | $V_{GS(th)}$ | 1.2 | 2    | 2.7 | Vdc |
| Gate Quiescent Voltage<br>( $V_{DD} = 32\text{ Vdc}$ , $I_{DA} = 150\text{ mAdc}$ , Measured in Functional Test) | $V_{GS(Q)}$  | 2   | 2.7  | 3.5 | Vdc |
| Drain-Source On-Voltage<br>( $V_{GS} = 10\text{ Vdc}$ , $I_D = 0.325\text{ Adc}$ )                               | $V_{DS(on)}$ | 0.1 | 0.24 | 0.3 | Vdc |

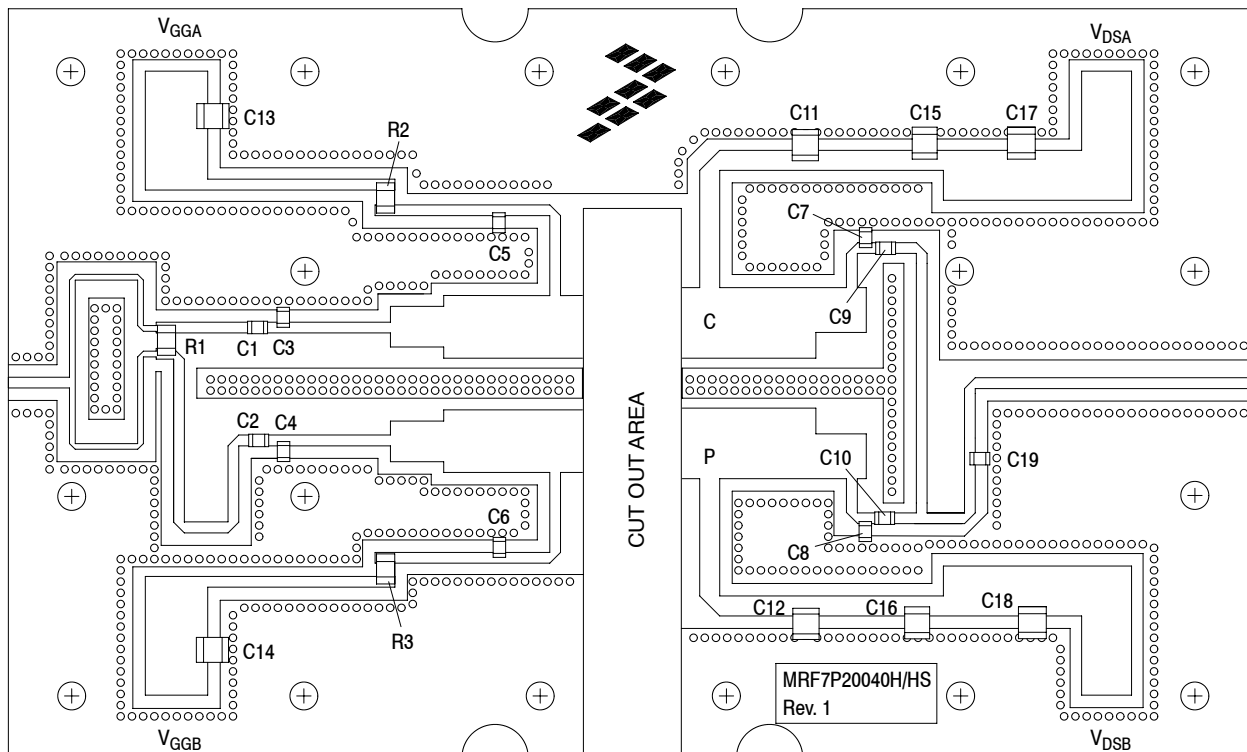
**Functional Tests** <sup>(2,3)</sup> (In Freescale Doherty Test Fixture, 50 ohm system)  $V_{DD} = 32\text{ Vdc}$ ,  $I_{DQA} = 150\text{ mA}$ ,  $V_{GSB} = 1.5\text{ Vdc}$ ,  $P_{out} = 10\text{ W Avg.}$ ,  $f = 2025\text{ MHz}$ , Single-Carrier W-CDMA, IQ Magnitude Clipping, Input Signal PAR = 9.9 dB @ 0.01% Probability on CCDF. ACPR measured in 3.84 MHz Channel Bandwidth @  $\pm 5\text{ MHz}$  Offset.

|                                                          |          |     |       |     |     |
|----------------------------------------------------------|----------|-----|-------|-----|-----|
| Power Gain                                               | $G_{ps}$ | 16  | 18.2  | 21  | dB  |
| Drain Efficiency                                         | $\eta_D$ | 39  | 42.6  | —   | %   |
| Output Peak-to-Average Ratio @ 0.01% Probability on CCDF | PAR      | 6.9 | 7.3   | —   | dB  |
| Adjacent Channel Power Ratio                             | ACPR     | —   | -34.8 | -30 | dBc |
| Input Return Loss                                        | IRL      | —   | -17.8 | -10 | dB  |

**Typical Performance** <sup>(3)</sup> (In Freescale Doherty Test Fixture, 50 ohm system)  $V_{DD} = 32\text{ Vdc}$ ,  $I_{DQA} = 150\text{ mA}$ ,  $V_{GSB} = 1.5\text{ Vdc}$ , 2010–2025 MHz Bandwidth

|                                                                                                                                                                                    |                      |   |       |   |                      |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------|---|-------|---|----------------------|
| $P_{out}$ @ 1 dB Compression Point, CW                                                                                                                                             | P1dB                 | — | 35    | — | W                    |
| $P_{out}$ @ 3 dB Compression Point, CW <sup>(4)</sup>                                                                                                                              | P3dB                 | — | 50    | — | W                    |
| IMD Symmetry @ 15 W PEP, $P_{out}$ where IMD Third Order Intermodulation $\cong 30\text{ dBc}$<br>(Delta IMD Third Order Intermodulation between Upper and Lower Sidebands > 2 dB) | IMD <sub>sym</sub>   | — | 8     | — | MHz                  |
| VBW Resonance Point<br>(IMD Third Order Intermodulation Inflection Point)                                                                                                          | VBW <sub>res</sub>   | — | 70    | — | MHz                  |
| Gain Flatness in 15 MHz Bandwidth @ $P_{out} = 10\text{ W Avg.}$                                                                                                                   | $G_F$                | — | 0.04  | — | dB                   |
| Gain Variation over Temperature<br>( $-30^\circ\text{C}$ to $+85^\circ\text{C}$ )                                                                                                  | $\Delta G$           | — | 0.013 | — | dB/ $^\circ\text{C}$ |
| Output Power Variation over Temperature<br>( $-30^\circ\text{C}$ to $+85^\circ\text{C}$ ) <sup>(4)</sup>                                                                           | $\Delta P1\text{dB}$ | — | 0.006 | — | dB/ $^\circ\text{C}$ |

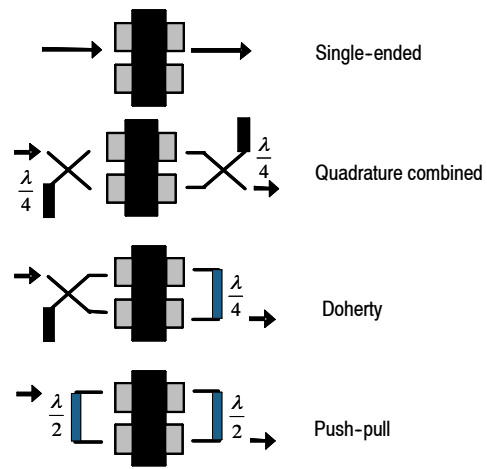
- Each side of device measured separately.
- Part internally matched both on input and output.
- Measurement made with device in a Symmetrical Doherty configuration.
- Exceeds recommended operating conditions. See CW operation data in Maximum Ratings table.



**Figure 2. MRF7P20040HR3(HSR3) Test Circuit Component Layout**

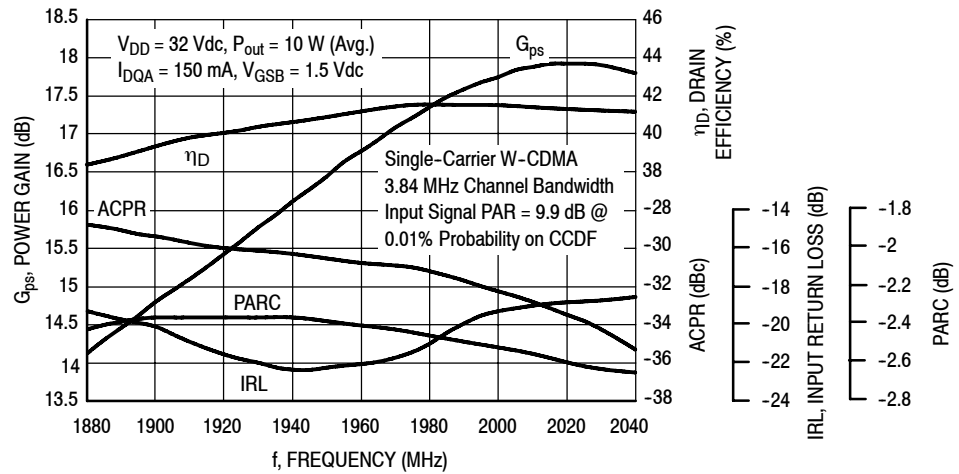
**Table 5. MRF7P20040HR3(HSR3) Test Circuit Component Designations and Values**

| Part            | Description                        | Part Number        | Manufacturer |
|-----------------|------------------------------------|--------------------|--------------|
| C1, C2, C9, C10 | 12 pF Chip Capacitors              | ATC600F120FT250XT  | ATC          |
| C3, C4          | 2.4 pF Chip Capacitors             | ATC600F2R4AT250XT  | ATC          |
| C5, C6          | 27 pF Chip Capacitors              | ATC600F270FT250XT  | ATC          |
| C7, C8          | 1.1 pF Chip Capacitors             | ATC600F1R1AT250XT  | ATC          |
| C11, C12        | 12 pF Chip Capacitors              | ATC100B120FT1500XT | ATC          |
| C13, C14        | 2.2 $\mu$ F, 50 V Chip Capacitors  | C3225X7R1H225KT    | TDK          |
| C15, C16        | 4.7 $\mu$ F, 50 V Chip Capacitors  | GRM43ER61H475MA88L | Murata       |
| C17, C18        | 10 $\mu$ F, 50 V Chip Capacitors   | GRM55DR61H106KA88L | Murata       |
| C19             | 0.8 pF Chip Capacitor              | ATC600F0R8AT250XT  | ATC          |
| R1              | 100 $\Omega$ , 1/4 W Chip Resistor | CRCW12061000FKEA   | Vishay       |
| R2, R3          | 12 $\Omega$ , 1/4 W Chip Resistors | CRCW120612R0FKEA   | Vishay       |
| PCB             | 0.020", $\epsilon_r = 3.5$         | RO4350B            | Rogers       |

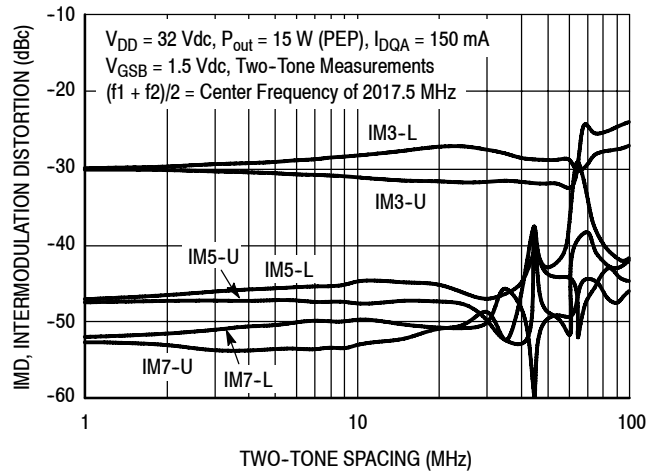


**Figure 3. Possible Circuit Topologies**

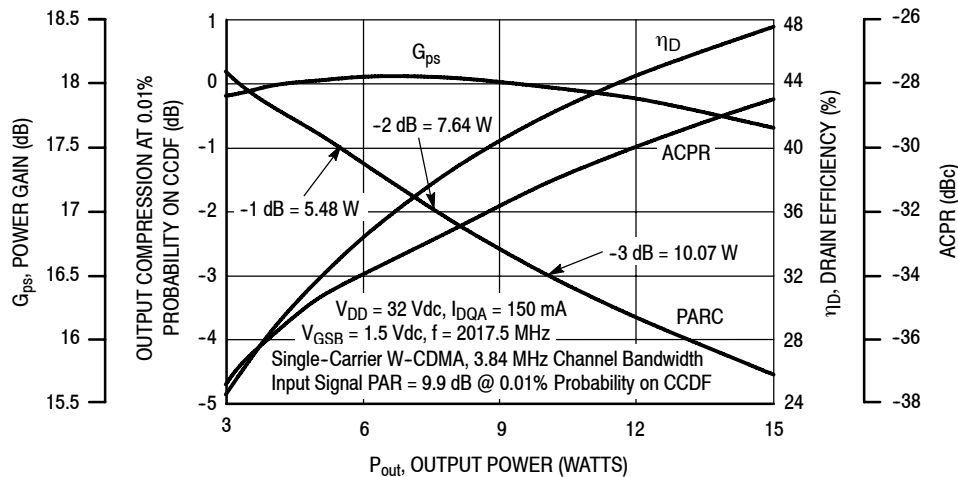
## TYPICAL CHARACTERISTICS



**Figure 4. Output Peak-to-Average Ratio Compression (PARC)  
Broadband Performance @  $P_{out} = 10$  Watts Avg.**

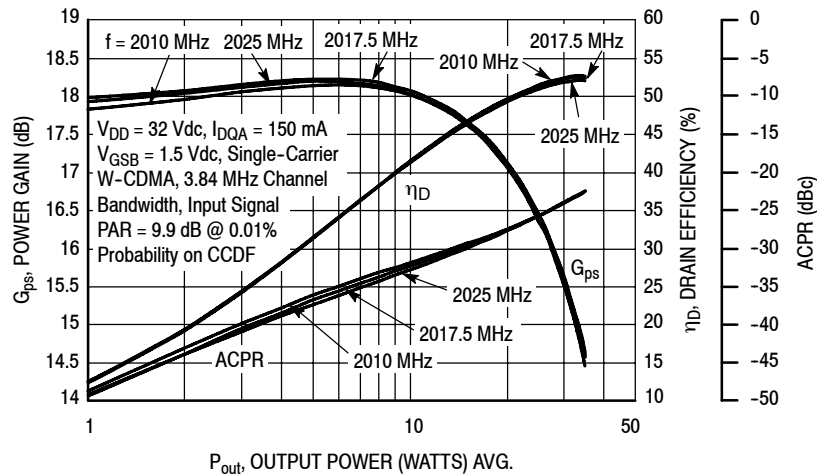


**Figure 5. Intermodulation Distortion Products  
versus Two-Tone Spacing**

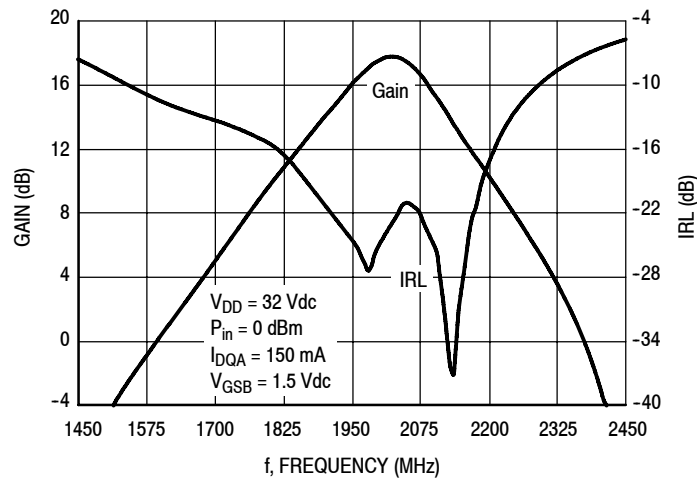


**Figure 6. Output Peak-to-Average Ratio  
Compression (PARC) versus Output Power**

## TYPICAL CHARACTERISTICS

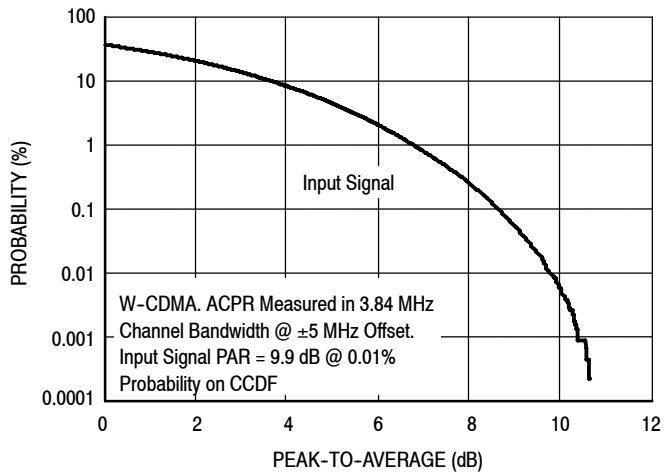


**Figure 7. Single-Carrier W-CDMA Power Gain, Drain Efficiency and ACPR versus Output Power**

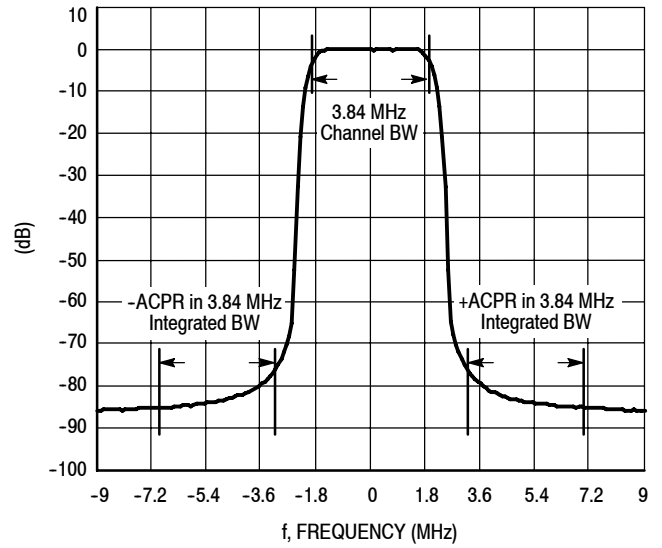


**Figure 8. Broadband Frequency Response**

## W-CDMA TEST SIGNAL



**Figure 9. CCDF W-CDMA IQ Magnitude Clipping, Single-Carrier Test Signal**



**Figure 10. Single-Carrier W-CDMA Spectrum**

$V_{DD} = 32 \text{ Vdc}$ ,  $I_{DQA} = 150 \text{ mA}$ ,  $V_{GSB} = 1.5 \text{ Vdc}$ ,  $P_{out} = 10 \text{ W Avg.}$

| f<br>MHz | $Z_{source}$<br>$\Omega$ | $Z_{load}$<br>$\Omega$ |
|----------|--------------------------|------------------------|
| 1995     | $6.80 - j13.11$          | $14.67 + j4.09$        |
| 2000     | $6.66 - j13.03$          | $14.87 + j3.82$        |
| 2005     | $6.52 - j12.93$          | $15.08 + j3.58$        |
| 2010     | $6.37 - j12.85$          | $15.27 + j3.29$        |
| 2015     | $6.22 - j12.78$          | $15.45 + j3.00$        |
| 2020     | $6.08 - j12.69$          | $15.62 + j2.77$        |
| 2025     | $5.94 - j12.60$          | $15.80 + j2.44$        |
| 2030     | $5.80 - j12.49$          | $15.95 + j2.14$        |
| 2035     | $5.65 - j12.40$          | $16.08 + j1.82$        |

Note: Measured with Peaking side open.

$Z_{load}$  = Test circuit impedance as measured from drain to ground.

$Z_{source}$  = Test circuit impedance as measured from gate to ground.

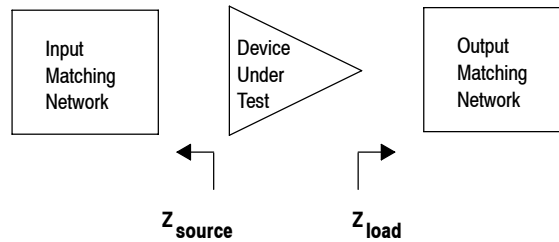


Figure 11. Series Equivalent Source and Load Impedance — Carrier Side

$V_{DD} = 32 \text{ Vdc}$ ,  $I_{DQA} = 150 \text{ mA}$ ,  $V_{GSB} = 1.5 \text{ Vdc}$ ,  $P_{out} = 10 \text{ W Avg.}$

| f<br>MHz | $Z_{source}$<br>$\Omega$ | $Z_{load}$<br>$\Omega$ |
|----------|--------------------------|------------------------|
| 1995     | $8.45 - j12.85$          | $5.83 - j10.09$        |
| 2000     | $8.28 - j12.79$          | $5.57 - j10.11$        |
| 2005     | $8.11 - j12.70$          | $5.32 - j10.08$        |
| 2010     | $7.95 - j12.63$          | $5.06 - j10.07$        |
| 2015     | $7.79 - j12.56$          | $4.80 - j10.06$        |
| 2020     | $7.63 - j12.48$          | $4.55 - j10.01$        |
| 2025     | $7.50 - j12.40$          | $4.32 - j9.96$         |
| 2030     | $7.34 - j12.32$          | $4.06 - j9.88$         |
| 2035     | $7.19 - j12.24$          | $3.82 - j9.81$         |

Note: Measured with Carrier side open.

$Z_{load}$  = Test circuit impedance as measured from drain to ground.

$Z_{source}$  = Test circuit impedance as measured from gate to ground.

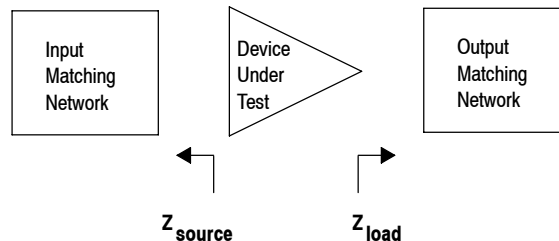
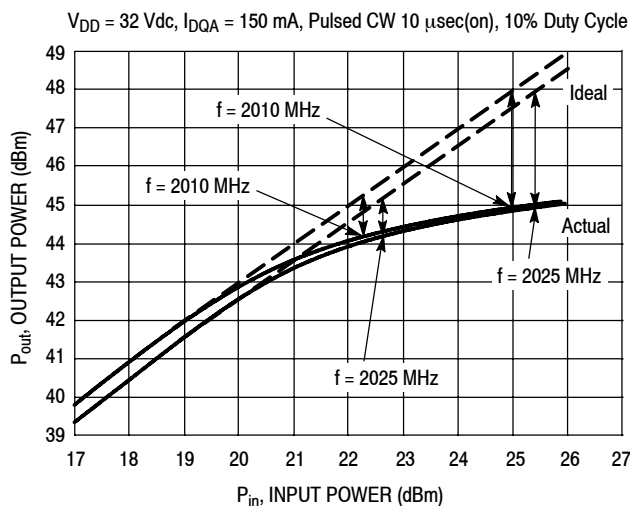


Figure 12. Series Equivalent Source and Load Impedance — Peaking Side

## ALTERNATIVE PEAK TUNE LOAD PULL CHARACTERISTICS



Load Pull Test Fixture Tuned for Peak P1dB Output Power @ 32 V

| f<br>(MHz) | P1dB  |      | P3dB  |      |
|------------|-------|------|-------|------|
|            | Watts | dBm  | Watts | dBm  |
| 2010       | 26    | 44.1 | 31    | 44.9 |
| 2025       | 26    | 44.2 | 31    | 44.9 |

Test Impedances per Compression Level

| f<br>(MHz) |      | $Z_{source}$<br>$\Omega$ | $Z_{load}$<br>$\Omega$ |
|------------|------|--------------------------|------------------------|
| 2010       | P1dB | $2.49 - j18.56$          | $15.82 - j0.28$        |
| 2025       | P1dB | $2.66 - j19.78$          | $15.78 + j0.52$        |

**Figure 13. Pulsed CW Output Power  
versus Input Power @ 32 V**

**NOTE:** Measurement made on the Class AB, carrier side of the device.

$$V_{DD} = 28 \text{ Vdc}, I_{DQA} = 150 \text{ mA}$$

| f<br>MHz | Max P <sub>out</sub> <sup>(1)</sup> |      | Z <sub>source</sub><br>Ω | Z <sub>load</sub><br>Ω |
|----------|-------------------------------------|------|--------------------------|------------------------|
|          | Watts                               | dBm  |                          |                        |
| 1805     | 35                                  | 45.4 | 2.2 - j9.3               | 17.1 - j7.9            |
| 1880     | 35                                  | 45.5 | 2.3 - j11.3              | 14.0 - j4.2            |
| 1930     | 35                                  | 45.5 | 2.4 - j13.0              | 14.7 - j5.9            |
| 2025     | 35                                  | 45.5 | 3.5 - j17.3              | 15.5 - j8.0            |
| 2110     | 34                                  | 45.3 | 3.8 - j20.6              | 15.4 - j9.3            |
| 2200     | 35                                  | 45.5 | 5.6 - j25.8              | 14.4 - j9.4            |

(1) Maximum output power measurement reflects pulsed 3 dB gain compression.

Z<sub>source</sub> = Test circuit impedance as measured from gate contact to ground.

Z<sub>load</sub> = Test circuit impedance as measured from drain contact to ground.

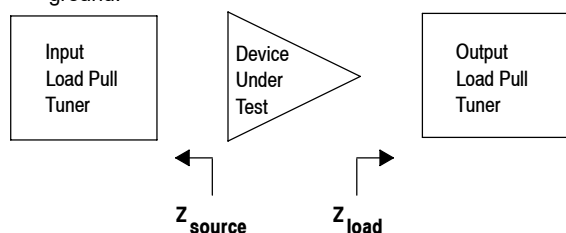


Figure 14. Carrier Side Load Pull Performance — Maximum P3dB Tuning

$$V_{DD} = 28 \text{ Vdc}, I_{DQA} = 150 \text{ mA}$$

| f<br>MHz | Max Eff. <sup>(1)</sup><br>% | Z <sub>source</sub><br>Ω | Z <sub>load</sub><br>Ω |
|----------|------------------------------|--------------------------|------------------------|
|          |                              |                          |                        |
| 1805     | 66.6                         | 2.2 - j9.3               | 17.6 + j9.5            |
| 1880     | 70.1                         | 2.3 - j11.3              | 16.1 + j9.8            |
| 1930     | 69.8                         | 2.4 - j13.0              | 14.2 + j8.9            |
| 2025     | 67.7                         | 3.5 - j17.3              | 13.8 + j6.2            |
| 2110     | 67.9                         | 3.8 - j20.6              | 11.5 + j3.9            |
| 2200     | 70.3                         | 5.6 - j25.8              | 9.6 - j0.6             |

(1) Maximum efficiency measurement reflects pulsed 3 dB gain compression.

Z<sub>source</sub> = Test circuit impedance as measured from gate contact to ground.

Z<sub>load</sub> = Test circuit impedance as measured from drain contact to ground.

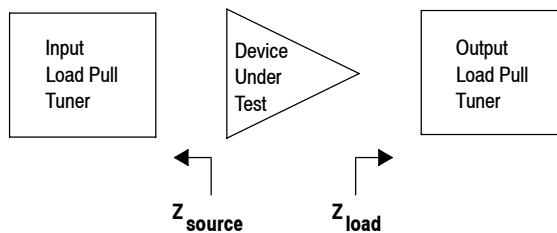
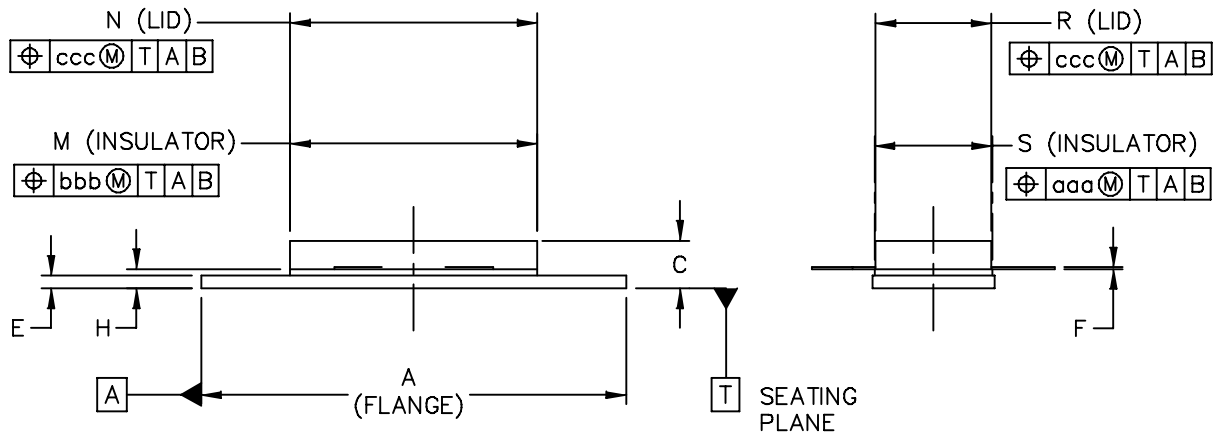


Figure 15. Carrier Side Load Pull Performance — Maximum Efficiency Tuning

Technical drawing of a mechanical assembly showing a cross-section of a housing with internal features and dimensions. The drawing includes the following labels and dimensions:

- Dimensions:**
  - $G$ : Overall width of the housing.
  - $B$ : Thickness of the flange.
  - $4X K$ : Distance from the flange to the center of the first internal feature.
  - $4X J$ : Distance between the centers of the two internal features.
  - $4X AB$ : Distance from the center of the second internal feature to the right edge of the housing.
- Internal Features:**
  - $1'$  and  $2'$ : Top internal features.
  - $3'$  and  $4$ : Bottom internal features.
  - $5$ : Right internal feature.
- Annotations:**
  - $4X Z (LID)$ : Label pointing to the top surface of the housing.
  - $2X \varnothing Q$ : Label pointing to the two circular holes on the right side.
- Feature Callouts:**
  - Top left:  $\oplus$   $\varnothing bbb$   $\textcircled{M}$   $T$   $A$   $B$
  - Bottom left:  $\oplus$   $\varnothing bbb$   $\textcircled{M}$   $T$   $A$   $B$
  - Bottom right:  $\oplus$   $\varnothing bbb$   $\textcircled{M}$   $T$   $A$   $B$

MRF7P20040HR3 MRF7P20040HSR3

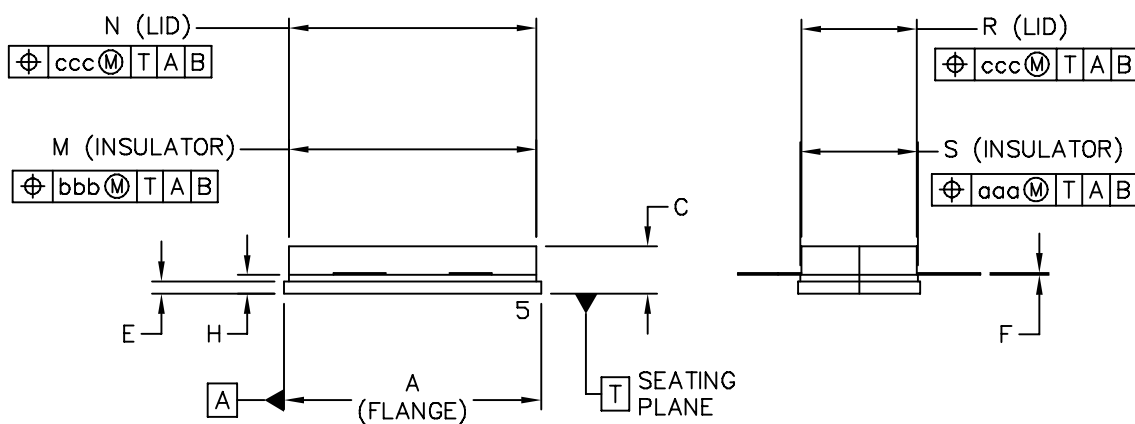
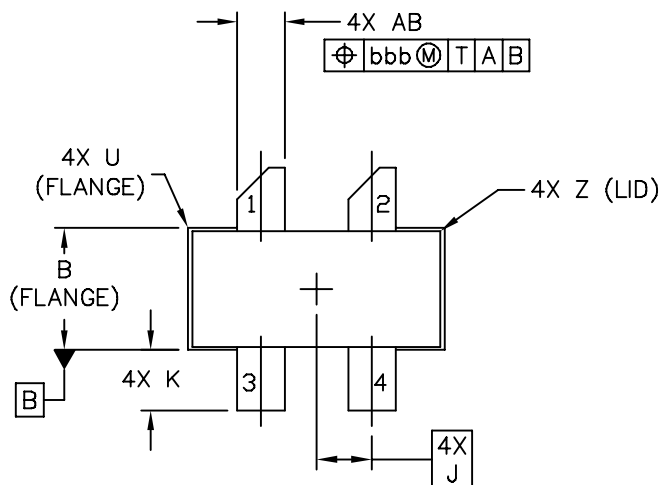
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION H IS MEASURED .030 (0.762) AWAY FROM PACKAGE BODY.

STYLE 1:

- PIN 1. DRAIN  
2. DRAIN  
3. GATE  
4. GATE  
5. SOURCE

| INCH                                                    |           |       | MILLIMETER         |       | INCH                     |                            |      | MILLIMETER  |      |
|---------------------------------------------------------|-----------|-------|--------------------|-------|--------------------------|----------------------------|------|-------------|------|
| DIM                                                     | MIN       | MAX   | MIN                | MAX   | DIM                      | MIN                        | MAX  | MIN         | MAX  |
| A                                                       | 1.335     | 1.345 | 33.91              | 34.16 | R                        | .365                       | .375 | 9.27        | 9.53 |
| B                                                       | .380      | .390  | 9.65               | 9.91  | S                        | .365                       | .375 | 9.27        | 9.52 |
| C                                                       | .125      | .170  | 3.18               | 4.32  | U                        |                            | .040 |             | 1.02 |
| E                                                       | .035      | .045  | 0.89               | 1.14  | Z                        |                            | .030 |             | 0.76 |
| F                                                       | .003      | .006  | 0.08               | 0.15  | AB                       | .145                       | .155 | 3.68        | 3.94 |
| G                                                       | 1.100 BSC |       | 27.94 BSC          |       |                          |                            |      |             |      |
| H                                                       | .057      | .067  | 1.45               | 1.7   | aaa                      | .005                       |      | 0.127       |      |
| J                                                       | .175 BSC  |       | 4.44 BSC           |       | bbb                      | .010                       |      | 0.254       |      |
| K                                                       | .170      | .210  | 4.32               | 5.33  | ccc                      | .015                       |      | 0.381       |      |
| M                                                       | .774      | .786  | 19.61              | 20.02 |                          |                            |      |             |      |
| N                                                       | .772      | .788  | 19.61              | 20.02 |                          |                            |      |             |      |
| Q                                                       | ø.118     | ø.138 | ø3                 | ø3.51 |                          |                            |      |             |      |
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|                                                         |           |       |                    |       | STANDARD: NON-JEDEC      |                            |      |             |      |



|                                                         |  |                          |  |                            |  |
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|                                                         |  | CASE NUMBER: 465H-02     |  | 27 MAR 2007                |  |
|                                                         |  | STANDARD: NON-JEDEC      |  |                            |  |

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.
2. CONTROLLING DIMENSION: INCH.
3. DELETED
4. DIMENSION H IS MEASURED .030 (0.762) AWAY FROM PACKAGE BODY.

STYLE 1:

- PIN 1. DRAIN  
 2. DRAIN  
 3. GATE  
 4. GATE  
 5. SOURCE

| INCH                                                    |          |      | MILLIMETER         |       | INCH                     |                            |      | MILLIMETER  |        |
|---------------------------------------------------------|----------|------|--------------------|-------|--------------------------|----------------------------|------|-------------|--------|
| DIM                                                     | MIN      | MAX  | MIN                | MAX   | DIM                      | MIN                        | MAX  | MIN         | MAX    |
| A                                                       | .805     | .815 | 20.45              | 20.7  | U                        |                            | .040 |             | 1.02   |
| B                                                       | .380     | .390 | 9.65               | 9.91  | Z                        |                            | .030 |             | 0.76   |
| C                                                       | .125     | .170 | 3.18               | 4.32  | AB                       | .145                       | .155 | 3.68        | – 3.94 |
| E                                                       | .035     | .045 | 0.89               | 1.14  |                          |                            |      |             |        |
| F                                                       | .003     | .006 | 0.08               | 0.15  | aaa                      |                            | .005 |             | 0.127  |
| H                                                       | .057     | .067 | 1.45               | 1.7   | bbb                      |                            | .010 |             | 0.254  |
| J                                                       | .175 BSC |      | 4.44 BSC           |       | ccc                      |                            | .015 |             | 0.381  |
| K                                                       | .170     | .210 | 4.32               | 5.33  |                          |                            |      |             |        |
| M                                                       | .774     | .786 | 19.61              | 20.02 |                          |                            |      |             |        |
| N                                                       | .772     | .788 | 19.61              | 20.02 |                          |                            |      |             |        |
| R                                                       | .365     | .375 | 9.27               | 9.53  |                          |                            |      |             |        |
| S                                                       | .365     | .375 | 9.27               | 9.52  |                          |                            |      |             |        |
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| TITLE:<br><br>NI 780S-4                                 |          |      |                    |       | DOCUMENT NO: 98ASA10718D |                            |      | REV: A      |        |
|                                                         |          |      |                    |       | CASE NUMBER: 465H-02     |                            |      | 27 MAR 2007 |        |
|                                                         |          |      |                    |       | STANDARD: NON-JEDEC      |                            |      |             |        |

## PRODUCT DOCUMENTATION, TOOLS AND SOFTWARE

Refer to the following documents, tools and software to aid your design process.

### Application Notes

- AN1955: Thermal Measurement Methodology of RF Power Amplifiers

### Engineering Bulletins

- EB212: Using Data Sheet Impedances for RF LDMOS Devices

### Software

- Electromigration MTTF Calculator
- RF High Power Model
- .s2p File

For Software and Tools, do a Part Number search at <http://www.freescale.com>, and select the “Part Number” link. Go to the Software & Tools tab on the part’s Product Summary page to download the respective tool.

## R5 TAPE AND REEL OPTION

R5 Suffix = 50 Units, 56 mm Tape Width, 13 inch Reel.

The R5 tape and reel option for MRF7P20040H and MRF7P20040HS parts will be available for 2 years after release of MRF7P20040H and MRF7P20040HS. Freescale Semiconductor, Inc. reserves the right to limit the quantities that will be delivered in the R5 tape and reel option. At the end of the 2 year period customers who have purchased these devices in the R5 tape and reel option will be offered MRF7P20040H and MRF7P20040HS in the R3 tape and reel option.

## REVISION HISTORY

The following table summarizes revisions to this document.

| Revision | Date      | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         |
|----------|-----------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 0        | June 2009 | <ul style="list-style-type: none"><li>• Initial Release of Data Sheet</li></ul>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |
| 1        | Aug. 2009 | <ul style="list-style-type: none"><li>• Removed IQ Magnitude Clipping from Typical Performance bullet, p. 1 and Functional Test header, p. 2</li><li>• Electrical Characteristics, DC tests: updated footnote to indicate each side of device measured separately, p. 2</li></ul>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
| 2        | Dec. 2010 | <ul style="list-style-type: none"><li>• Updated frequency in overview paragraph from “2010 to 2025 MHz” to “1800 to 2200 MHz” per expanded load pull characterization shown in Fig. 14, Carrier Side Load Pull Performance — Maximum P3dB Tuning and Fig. 15, Carrier Side Load Pull Performance — Maximum Efficiency Tuning, p. 1</li><li>• Added CW Operation information to Maximum Ratings table, p. 1</li><li>• In Table 2, Thermal Characteristics, <math>P_{out} = 10</math> W CW thermal resistance values changed from <math>I_{DQA} 2.5/V_{GSB} 2.9</math> to <math>2.11^{\circ}\text{C/W}</math> and <math>P_{out} = 40</math> W CW thermal resistance value changed from 2.3 to <math>1.50^{\circ}\text{C/W}</math>. Thermal values now reflect the use of the combined dissipated power from the carrier amplifier and peaking amplifier, p. 1</li><li>• Added Fig. 14, Carrier Side Load Pull Performance — Maximum P3dB Tuning and Fig. 15, Carrier Side Load Pull Performance — Maximum Efficiency Tuning to show load pull data for expanded frequency range presented in p. 1 overview paragraph, p. 10</li></ul> |

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